



YEA SHIN TECHNOLOGY CO., LTD

MBRL1040FCT THRU MBRL10200FCT

10A Low V_F SCHOTTKY Barrier Rectifier

Voltage - 40 to 200 Volts Current – 10 Amperes

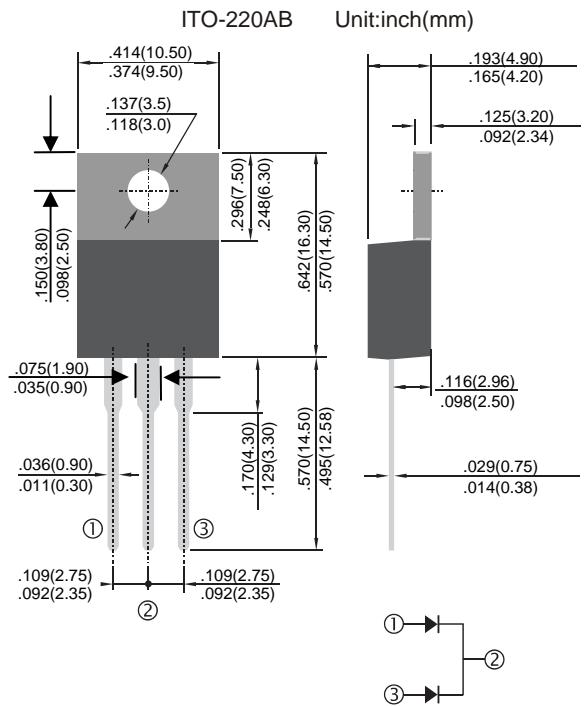


Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0.
 - Flame Retardant Epoxy Molding Compound.
 - Metal silicon junction, majority carrier conduction
 - Low power loss, high efficiency.
 - High current capability
 - For use in low voltage, high frequency inverters free wheeling, and polarity protection applications.
 - Lead free in comply with EU RoHS.

Mechanical Data

- Case: ITO-220AB molded plastic
 - Terminals: solder plated, solderable per MIL-STD-750, Method 2026
 - Polarity: As marked.
 - Mounting Position: Any



Maximum Ratings & Thermal Characteristics (Ratings at 25°C ambient temperature unless otherwise specified.)
(Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate by 20%)

Parameters	Symbol	MBRL 1040FCT	MBRL 1045FCT	MBRL 1060FCT	MBRL 10100FCT	MBRL 10200FCT	Unit
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	40	45	60	100	200	V
Maximum RMS Voltage	V _{RMS}	28	31.5	42	70	140	V
Maximum DC Blocking Voltage	V _{DC}	40	45	60	100	200	V
Maximum Average Froward Rectified Current	I _(AV)			10			A
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}			150			A
Maximum Instantaneous Forward Voltage at 5.0A Per Diode	V _F	0.45		0.5	0.6	0.85	V
Maximum DC Reverse Current Ta=25°C at Rated DC Blocking Voltage Ta=125°C	I _R	0.25 20 (Typ.)		0.12 12 (Typ.)	0.05 7.2(Typ.)		mA
Typical Junction Capacitance (Note 1)	C _J	500		300	620		pF
Maximum Thermal Resistance(Note 2)	R _{θJC}			15			°C/W
Operating Temperature Range	T _J			-55 to +150			°C
Storage Temperature Range	T _{STG}			-55 to +150			°C

Notes: 1. Measure at 1.0MHz and applied reverse voltage of 4.0 Vdc.

1. Measure at 1.0MHz and apply
2. Mounted on infinite heatsink

DEVICE CHARACTERISTICS

MBRL1040FCT THRU MBRL10200FCT

40-45V

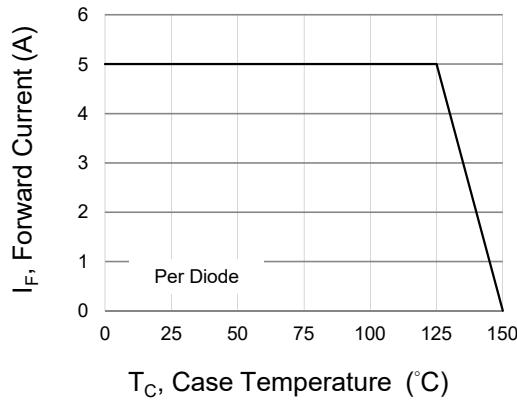


Fig.1 Forward Current Derating Curve

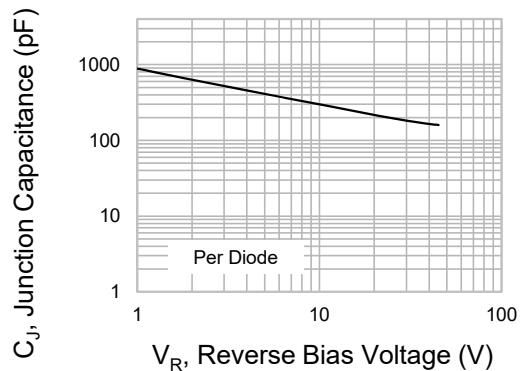


Fig.2 Typical Junction Capacitance

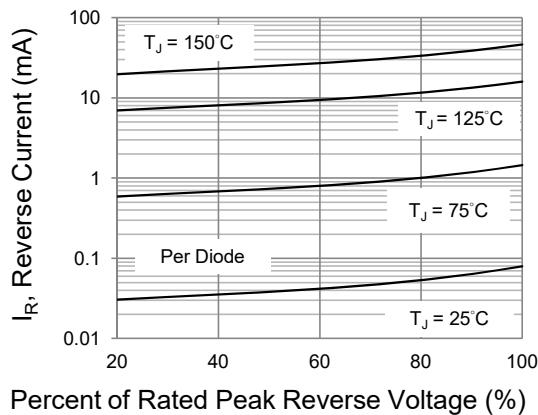


Fig.3 Typical Reverse Characteristics

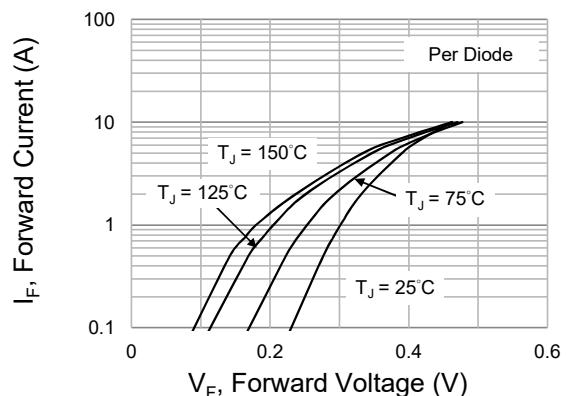


Fig.4 Typical Forward Characteristics

DEVICE CHARACTERISTICS

MBRL1040FCT THRU MBRL10200FCT

60V

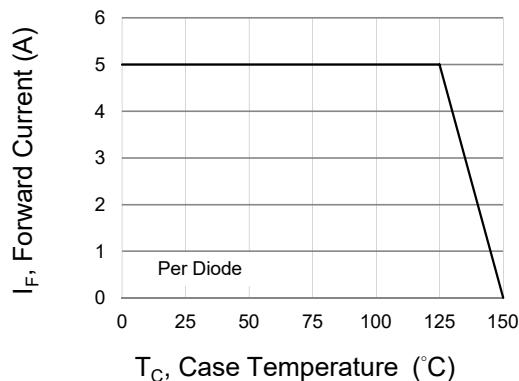


Fig.1 Forward Current Derating Curve

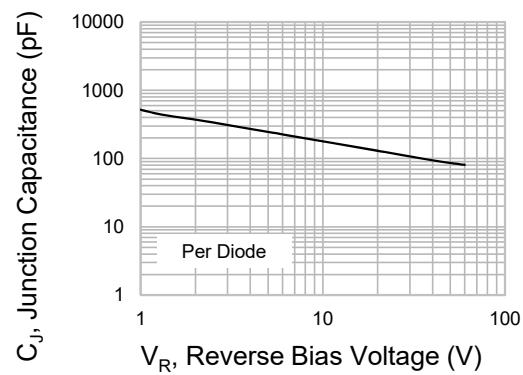


Fig.2 Typical Junction Capacitance

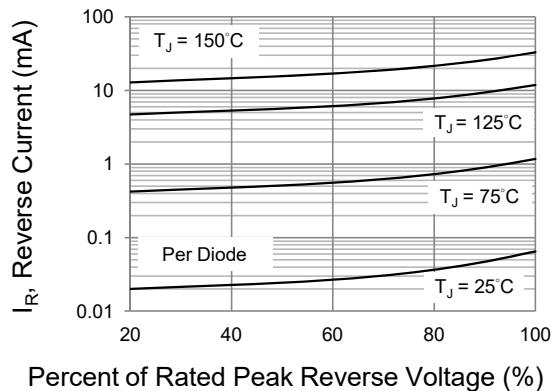


Fig.3 Typical Reverse Characteristics

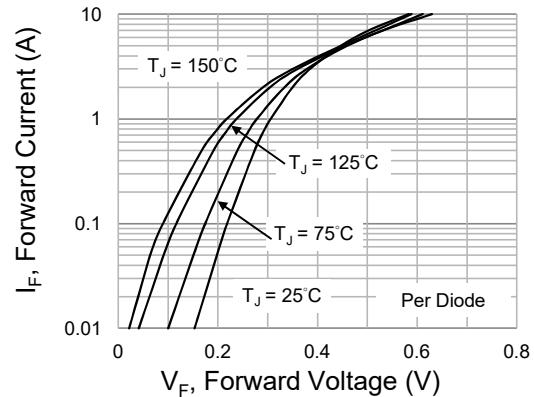


Fig.4 Typical Forward Characteristics

DEVICE CHARACTERISTICS

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100V

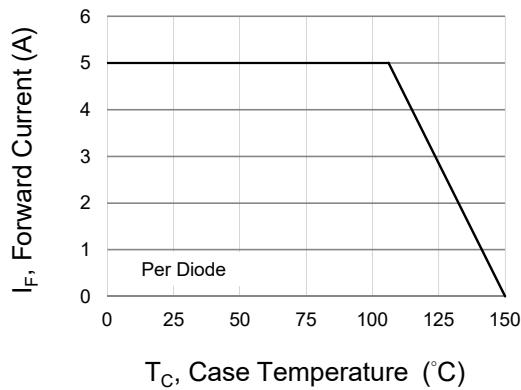


Fig.1 Forward Current Derating Curve

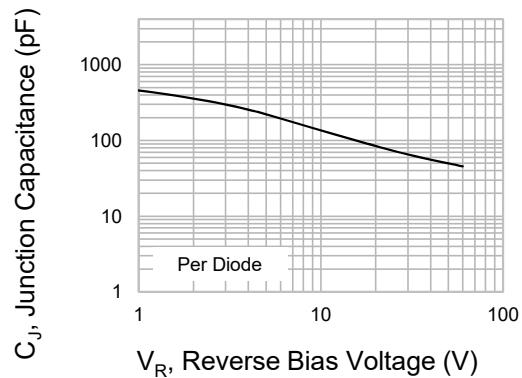


Fig.2 Typical Junction Capacitance

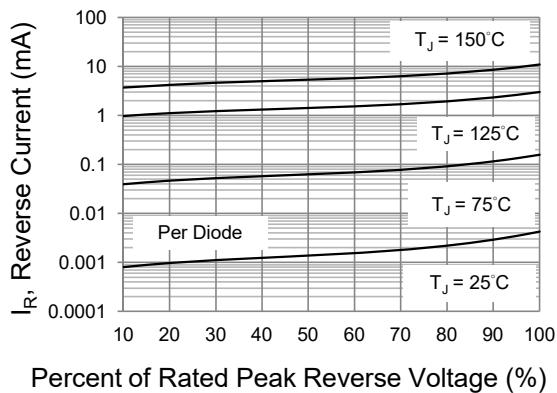


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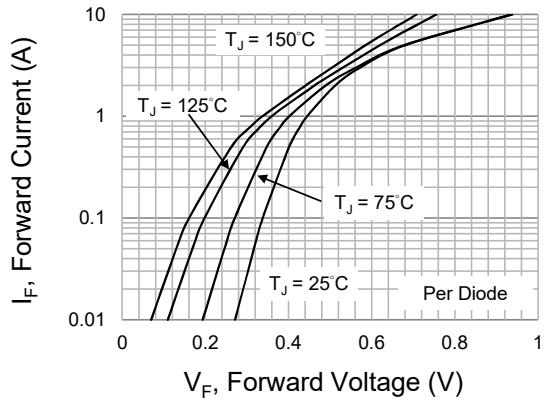


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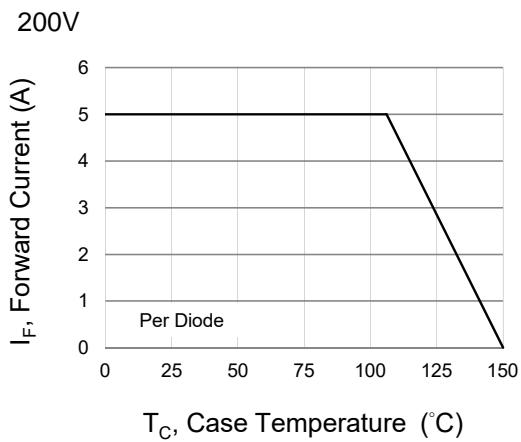


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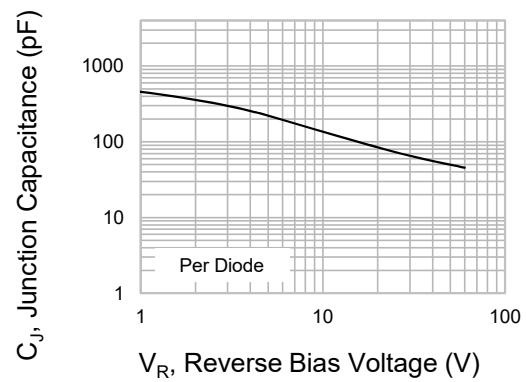


Fig.2 Typical Junction Capacitance

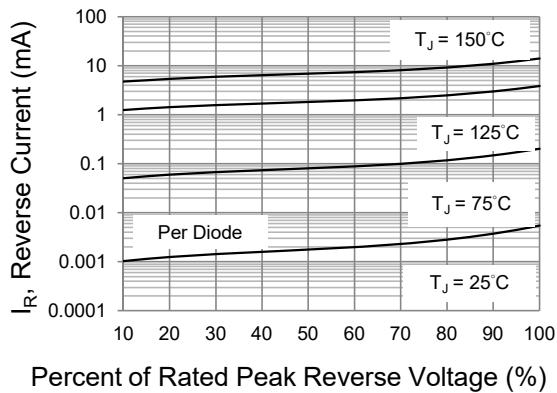


Fig.3 Typical Reverse Characteristics

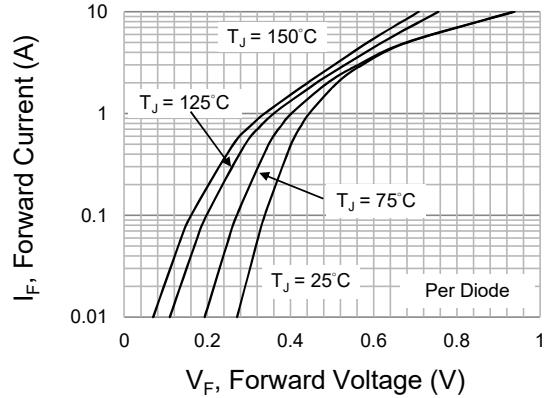


Fig.4 Typical Forward Characteristics